NSN 5961-01-342-0757

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View Online at https://aerobasegroup.com/nsn/5961-01-342-0757 **Inclosure Material:** Plastic **Overall Length:** Between 0.175 inches and 0.185 inches **Terminal Length:** 0.594 inches **Overall Height:** Between 0.135 inches and 0.145 inches **Overall Width:** Between 0.195 inches and 0.205 inches **End Application:** 6625-01-285-7241 modulator pulse **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-237 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 10.00 nanoamperes zero-gate-voltage source current preset **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: